

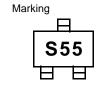
FJX4005R

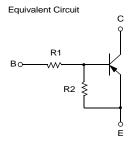
Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R_1 =4.7 $K\Omega$, R_2 =10 $K\Omega$)
- Complement to FJX3005R



1. Base 2. Emitter 3. Collector





PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-----------|-------|
| V_{CBO} | Collector-Base Voltage | -50 | V |
| V_{CEO} | Collector-Emitter Voltage | -50 | V |
| V_{EBO} | Emitter-Base Voltage | -10 | V |
| I _C | Collector Current | -100 | mA |
| P _C | Collector Power Dissipation | 200 | mW |
| TJ | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|--------------------------------|--------------------------------------|---|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I_{C} = -10 μ A, I_{E} =0 | -50 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | $I_C = -100 \mu A, I_B = 0$ | -50 | | | V |
| I _{CBO} | Collector Cut-off Current | V_{CB} = -40V, I_{E} =0 | | | -0.1 | μΑ |
| h _{FE} | DC Current Gain | V_{CE} = -5V, I_{C} = -5mA | 30 | | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I_{C} = -10mA, I_{B} = -0.5mA | | | -0.3 | V |
| C _{ob} | Output Capacitance | V _{CB} = -10V, I _E =0 f=1.0MHz | | 5.5 | | pF |
| f _T | Current Gain Bandwidth Product | V_{CE} = -10V, I_{C} = -5mA | | 200 | | MHz |
| V _I (off) | Input Off Voltage | V_{CE} = -5V, I_{C} = -100 μ A | -0.3 | | | V |
| V _I (on) | Input On Voltage | V_{CE} = -0.3V, I_{C} = -20mA | | | -2.5 | V |
| R ₁ | Input Resistor | | 3.2 | 4.7 | 6.2 | ΚΩ |
| R ₁ /R ₂ | Resistor Ratio | | 0.42 | 0.47 | 0.52 | |

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Typical Characteristics

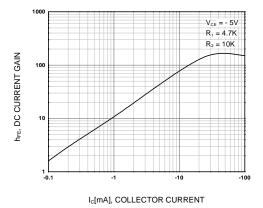


Figure 1. DC current Gain

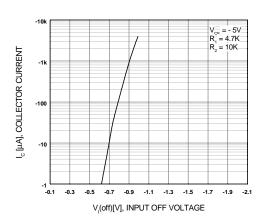


Figure 3. Input Off Voltage

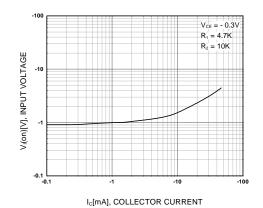


Figure 2. Input On Voltage

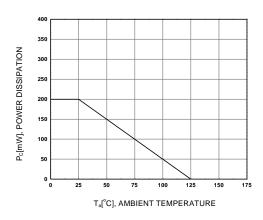
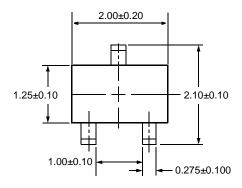


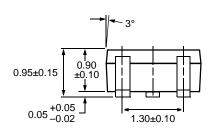
Figure 4. Power Derating

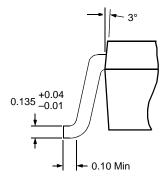
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Package Dimensions

SOT-323







Dimensions in Millimeters

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